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Final Proceedings of
The EOARD/IRC-sponsored
International Workshop on Gamma
Aluminide Alloy Technology

held from 1 to 3 May 1996 at The IRC in Materials for High Performance Applications The University of Birmingham

SECTION ONE

DTIC QUALITY INSPECTED 3

The organisers wish to thank the United States Air Force European Office of Aerospace Research and Development for its contributions to the success of this conference

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Contents

- 1. Foreword/Summary
- 2. Pre-conference literature, including workshop programme
- 3. Presentation Material:
 - F Appel
 - P Bowen
 - L Christodoulou
 - C Dimitrov
 - A Dowson
 - Y-W Kim
 - C Lang
 - M H Loretto
 - S Naka
 - P Threadgill

Foreword/Summary

The Workshop was organised jointly by Dr Young-Won Kim (UES, USA) and Professor Paul Bowen (University of Birmingham, UK), and was attended by fifty-four delegates. These included international representatives from the USA, France, Germany and the UK. In addition, two representatives attended on behalf of EOARD (ONR). The attendance list was, of course, dominated by UK delegates, but invited technical contributions were split as follows: seven sessions from the USA; four sessions from the UK; three sessions from France and two sessions from Germany.

The Workshop was built primarily around major contributions from Dr Young-Won Kim, and from individual speakers representing European countries with significant interests in the development of gamma-based titanium aluminide alloys. It thus afforded a unique opportunity to assess the relative progress of such alloys in the USA and Europe. The Workshop appeared to achieve its stated primary objective of providing focused academic debate on issues of fundamental understanding, and on how these alloys are likely to be introduced into the market place. The Workshop was both stimulating and informative, and favourable feedback from delegates was received by the organisers. Most important, it appears that the future of gamma based alloys is secure for selected aerospace, power generation and automotive applications.

Enclosed for reference are copies of the overheads used in presentations by invited contributors.

P Bowen April 1997

Joint EOARD/IRC-sponsored International Workshop on Gamma Aluminide Alloy Technology

Wednesday 1 May to Friday 3 May 1996

This will be a short, intensive three-day workshop on fundamental and technological aspects of gamma based titanium aluminide alloys. It is intended that the conference will have twelve formal invited papers: approximately six from the USA and six from Europe. In addition, shorter focused presentations from delegates will also be encouraged. Attendance will be by invitation only from industrial companies, academic institutions and research organisations. It is anticipated that the audience will be limited to fifty delegates in order to facilitate useful discussion. The programme will allow ample time for discussion groups to meet on an informal basis, and there will be a focused summary discussion on the third day of the conference.

Topics to be included are:

Fundamentals of behaviour
Processing
Microstructural development and control
Microstructure - property relationships
Damage tolerance and life prediction
Alloy development design
Property improvements
Component-specific alloy design
Joining
Applications
Future R and D directions

Confirmed speakers include Dr Young-Won Kim, UES Inc, USA; Professor P Bowen, The University of Birmingham, UK; Dr F Appel, GKSS, Germany; Dr S Naka, ONERA, France; Professor M H Loretto, The University of Birmingham, UK. Formal contributions are also expected from several industrial and other research organisations.

Formal proceedings will not be published, but lecture notes and handouts will be made available to delegates. In addition, a summary document will be prepared following the conference and this will be distributed to all delegates. There will be no registration fee. The central aim of the workshop will be to encourage focused debate between academics and industrialists with a view to expediting the introduction of gamma based titanium aluminides into the market place. It is also anticipated that the workshop will contribute to underlying issues of fundamental understanding still required for this emerging class of engineering structural alloys.

We wish to thank the United States Air Force European Office of Aerospace Research and Development for its contribution to the success of this conference.

Joint EOARD/IRC International Workshop Gamma Aluminide Alloy Technology

Wednesday 1 May to Friday 3 May 1996

REGISTA	ATION FORM (Photocopie	es/racsimile co	pies are	accepi	able)
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Organisa	ition:	Address:			
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Accomm	<u>odation</u>				
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	eserve accommodation like us to reserve accommo			priate	boxes, if
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ii)	A local hotel				
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<u>Meals</u>					
	d dinner will be provided fo ck box if you would like to tak				lelegate.
Please re	turn this form to Professor P	Bowen, IRC/S	chool of	Metallu	irgy and

Materials, The University of Birmingham, Edgbaston, Birmingham B15 2TT, UK (Fax: 0121 414 5232)

Gamma Workshop

Wednesday 1 May to Friday 3 May 1996

PROGRAMME

Wedne	sday 1	Мау	
10.30	Registration and Coffee		
10.50	Welcome and Introduction to the Workshop		
11.00	Session One - Chairman: P Bowen		
	11.00	Fundamentals of behaviour - Y W Kim	
	12.00	Processing of gamma based aluminides - Y W Kim	
13.00	Lunch		
14.30	Sessio	n Two - Chairman: T Khan	
	14.30	Alloy development and microstructural behaviour - M H Loretto	
	15.15	Recent activities and future directions in the study of microstructures of gamma titanium aluminides - S Naka	
16.15	Tea		
16.45	Sessio	on Three - Chairman: S Naka	
	16.45	Microstructural development and control - Y W Kim	
	17.45	Microstructual development in gamma TiAl alloys containing dispersoids of Ti $\rm B_2$ - L Christodoulou	
	18.30	Discussion	
Thurso	lay 2 N	lay	
10.00	Sessio	n One - Chairman: I P Jones	
	10.00	Segregation in cast alloys - A Dowson	
	10.45	Coffee	
	11.15	Structural instabilities in the TiAl alloys with B2 structure: first principle approach - Dr Nguyen-Manh	
	11.45	Microstructure-property relationships - Y W Kim	
13.00	Lunch		
14.15	Sessio	n Two - Chairman: Y W Kim	
	14.15	Overview of joining of gamma alloys - P Threadgill	
	15.15	Mechanical behaviour of extruded gamma alloys - M Winstone	
16.00	Tea		

16.30 Session Three - Chairman: J Petit

- 16.30 Fatigue crack propagation in gamma aluminide alloys C Mabru
- 16.50 Fatigue crack growth behaviour in titanium alloys and titanium aluminides S Listerin
- 17.10 Design against fracture and fatigue failure in gamma based alloys P Bowen
- 18.00 Discussion

Friday 3 May

9.15 Session One - Chairman: Y W Kim

- 9.15 High temperature deformation mechanisms in solution and and precipitation hardened two-phase titanium aluminide alloys - F Appel
- 10.00 Preliminary results on point defects, atomic mobility and creep in model TiAl compounds C Dimitrov
- 10.25 The role of the initial steps of oxidation for high temperature oxidation resistance C Lang
- 10.50 Discussion
- 11.10 Coffee

11.30 Session Two - Chairman: M H Loretto

- 11.30 Industrial applications, component specific design, and future research and development directions Y W Kim
- 13.00 Lunch
- 14.30 General discussion and close of conference

High - Temperature Deformation Mechanisms in Solution and Precipitation Hardened Two-Phase Titanium Aluminides

F. Appel, U. Christoph, M. Oehring, and R. Wagner

Institute for Materials Research GKSS-Forschungszentrum Geesthacht D-21502 Geesthacht

High-temperature applications of titanium aluminides

- design requirements at intended service temperatures of about 700 °C:
 - high strength reasonable toughness
 - · microstructural stability
 - creep resistance corrosion resistance
 - problems at elevated temperatures:
 - · degradation of strength properties,
 - rate dependend deformation processes become important

$$\dot{\epsilon} = f \cdot \rho_m \ v_d = f \ \rho_m \ v_o \ exp - \Delta G/kT$$

present study

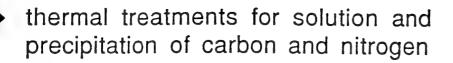
- mobilities and multiplication of dislocations
- structural stability
- metallurgical factors affecting high-temperature strength

Alloy compositions and microstructure

Composition (at.%)	Microstructure
Ti-48Al-2Cr	nearly-lamellar
Ti-47Al-2Cr-02Si	near gamma
	nearly-lamellar
Ti-47Al-1Cr +	fully-lamellar
+ Nb, Mn, Si, B	
Ti-49Al +	duplex and nearly
+ (60 - 1200) wt.ppm C	lamellar, depending
:	on C-conc

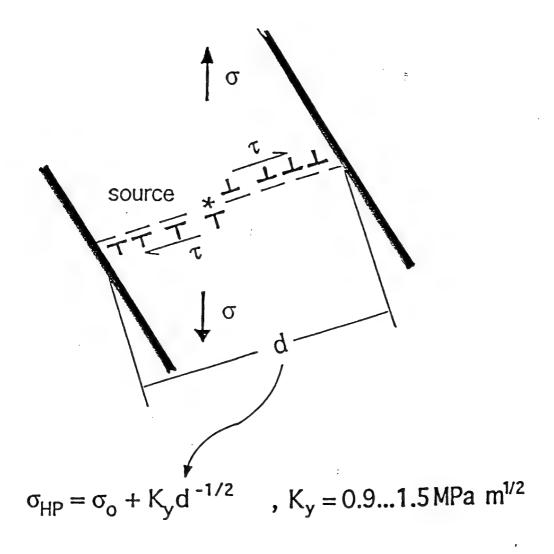
concentration of interstitial elements in the starting material

 N_2 : 100 - 200 wt. ppm 0_2 : 500 - 700 wt. ppm C: 100 - 200 wt. ppm



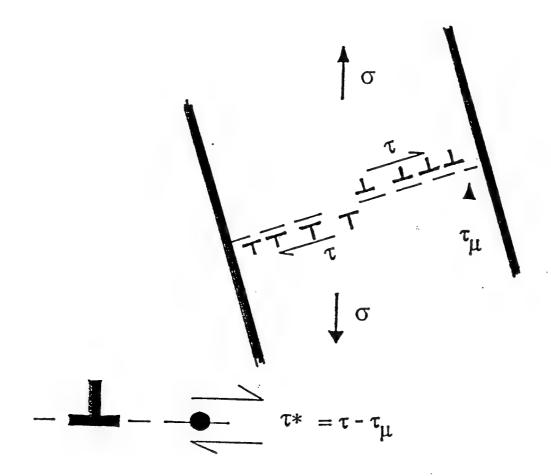
Strength properties of titanium aluminides

- Structure/property relationships usually described by Hall-Petch equations
- model bases on dislocation pileup theories



athermal stress contribution that is independent of temperature and strain rate

Factors governing the dislocation velocity



- friction forces due to
 - localized obstacles
 - lattice resistance
 - jog dragging
 - dislocation climb, etc.
- dislocation velocity

$$V_D = V_O \exp \left[-\Delta G (\tau^*) / kT\right]$$

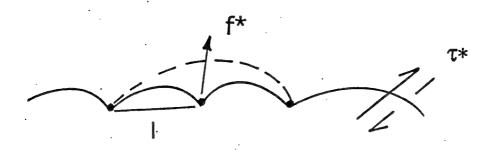
strain rate

$$\dot{a} = \rho_D b v_D = \dot{a}_O \exp \left[-\Delta G (\tau^*) / kT\right]$$

Thermal stress parts

Overcoming of glide obstacles with the aid of thermal activation

model



dislocation velocity

$$V_D = V_O \exp \left[-\Delta G (\tau^*) / kT\right]$$

strain rate

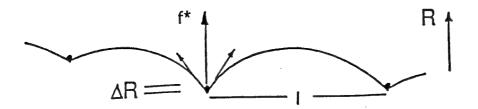
$$\dot{a} = \rho_D b V_D = \dot{a}_O \exp \left[-\Delta G (\tau^*) / kT\right]$$



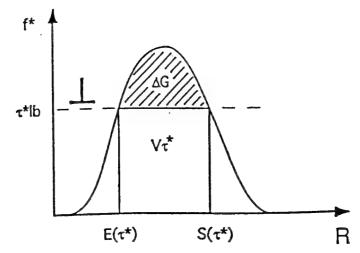
 τ^* described in terms of activation parameters

Dislocation mobilities

dislocation velocity: $v_d = v_0 \exp \Delta G(\tau^*)/kT$, described in terms of activation parameters



Energy profile characterizes obstacle strength



activation parameters:

$$V = I b \Delta R$$

 $\Delta F^* = \Delta G + V \tau^*$
 $\tau^* = (1/V) (\Delta F^* + k T ln å/å_0)$

Identification of relatively small and weak glide obstacles (solute atoms, jogs etc.)

Experimental methods

Changes of the mobile dislocation density and of the obstacle structure should be avoided

incremental changes of strain rate and temperature:

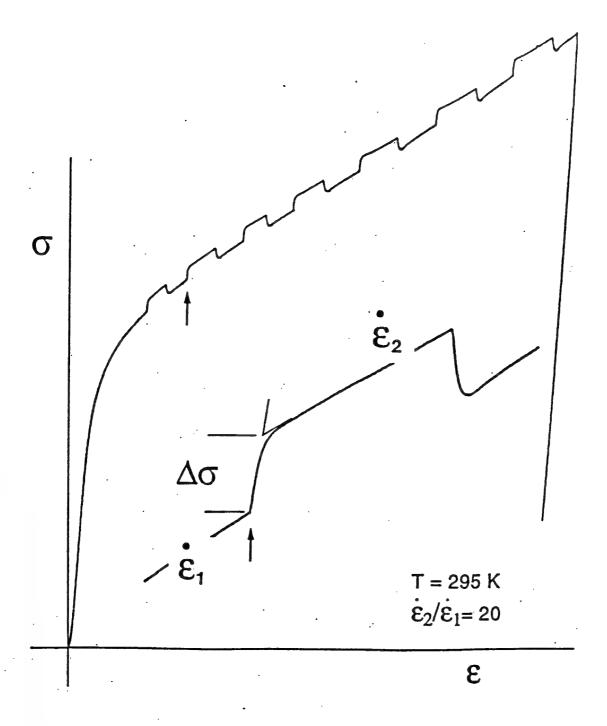
- $(\Delta\sigma/\Delta \ln \dot{\epsilon})_{T}$ strain rate cycling tests
- In $(-\dot{\sigma}) = f(\sigma)$ stress relaxation test
- $(\Delta \sigma/\Delta T)_{\dot{\epsilon}}$ temperature cycling tests

determination of these parameters as function of $\sigma,\,T$ and ϵ



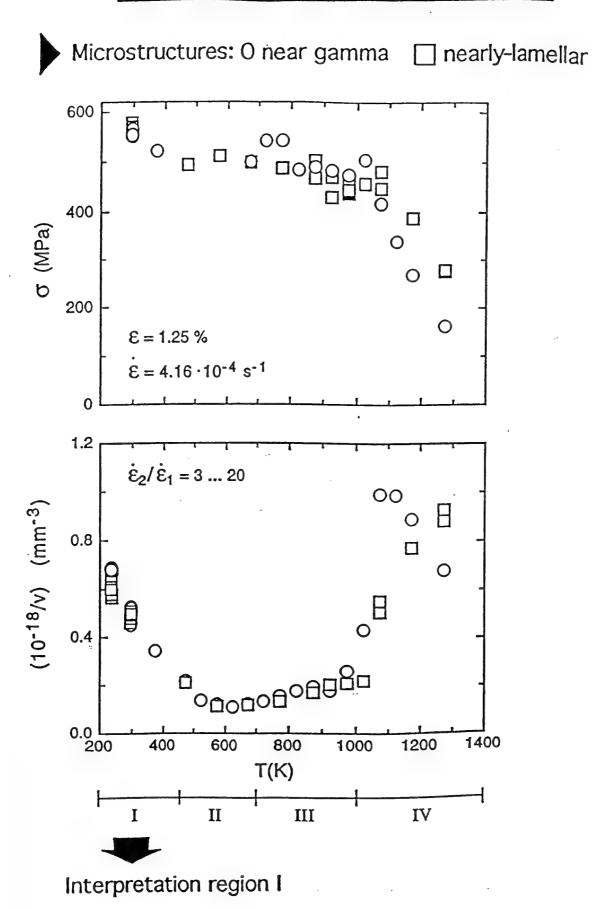
example: load elongation trace of a strain rate cycling test performed on ($\alpha_2 + \gamma$) TiAl

Estimation of activation parameters



Load elongation trace of a strain rate cycling test performed on an $(\alpha_2 + \gamma)$ TiAl alloy

Flow stresses and activation volumes



Athermal stress parts

$$\sigma_{\mu} = \sigma_{dis} + \sigma_{HP}$$

 σ_{dis} : long-range interaction of dislocations

$$\sigma_{dis} = f \alpha \mu b \rho^{1/2} = 30 \text{ MPa},$$

$$\rho = 10^8 \text{ cm}^{-2}$$
, $f = 3$, $\alpha = 0.5$

 σ_{HP} : interaction of dislocations with grain boundaries and lamellar interfaces

$$\sigma_{HP} = K_y d^{-1/2} = 400 MPa$$
,

$$d = 11.4 \mu m$$
, $K_y = 1.35 \text{ MPa m}^{1/2}$

athermal stress part arises mainly from interactions of dislocations with grain boundaries and lamellar interfaces

Activation parameters

near gamma microstructure

T = 300 K,
$$\varepsilon$$
 = 1.25%, $\dot{\varepsilon}$ = 4.16 * 10⁻⁴ s⁻¹

$$\sigma = 550 \text{ MPa}$$

$$\sigma_{\mu} = 430 \text{ MPa}$$

$$\tau^* = 40 \text{ MPa}$$

$$V = 95 b^3, b = 1/2 < 110$$

$$V \tau^* = 0.5 \text{ eV}$$

$$\Delta G = 0.8 \text{ eV}$$

$$\Delta F^* = \Delta G + V \tau^* = 1.3 \text{ eV}$$

low dislocation mobility



TEM-observations

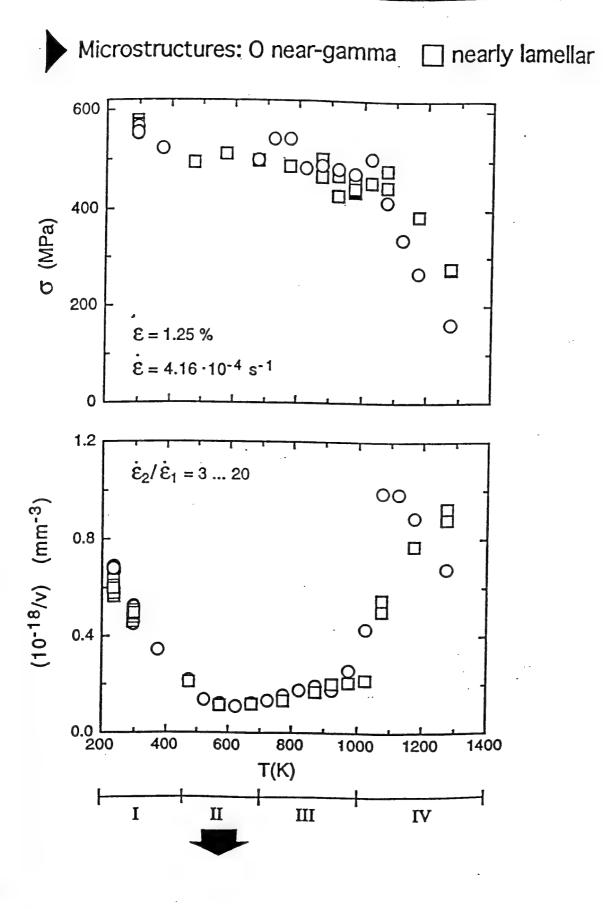


Pinning of 1/2 <110] screw dislocations by localized obstacles and jogs. (CM 3938)

Conclusions.

- The estimated activation parameters $\tau^* = 40 \text{ MPa}, \ V = 95 \text{ b}^3, \ \Delta G = 0.8 \text{ eV}, \ \Delta F^* = 1.3 \text{ eV}$ suggest a relatively low dislocation mobility at room temperature.
- The mobility of ordinary dislocations is controlled by the combined operation of localized pinning and lattice friction.
- A thermal stress part contributes with 20% to the total stress at room temperature.

Flow stresses and activation volumes

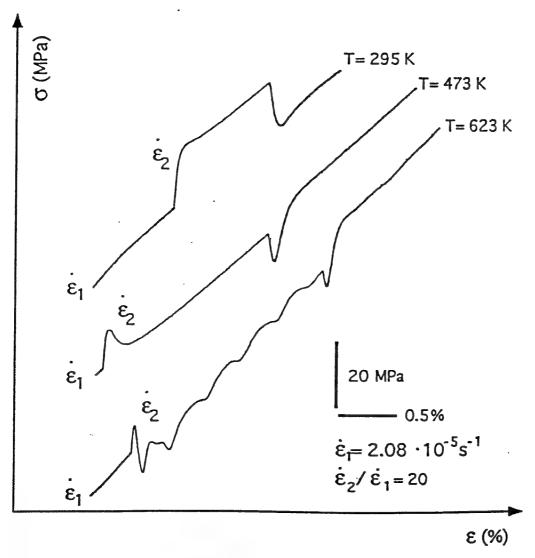


Temperature dependence of the flow stress

Region II: T = 450 ...700 K

Yield drop effects and serrations in a narrow temperature interval,

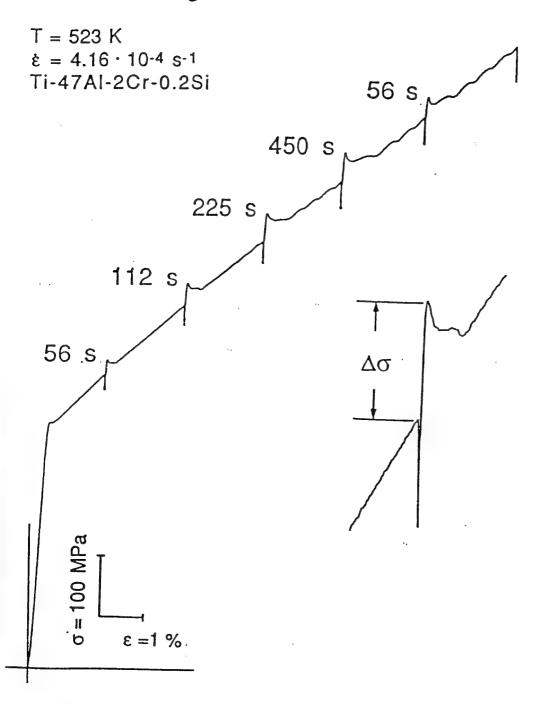
dependence on strain rate → load elongation traces





formation of impurity atmospheres, further investigations

load - elongation trace



experimental investigations

$$T = 300, 423, 523, 623 K$$

$$\dot{\epsilon} = 4.16 \cdot 10^{-4} \, \text{s}^{-1}$$

$$\Delta \sigma = f(T, t_a, \epsilon, \sigma_a, c_i)$$

$$\Delta \sigma = g (\sigma_a)$$

$$\Delta \sigma = h (t_a)$$

$$\Delta \sigma = u(\epsilon)$$

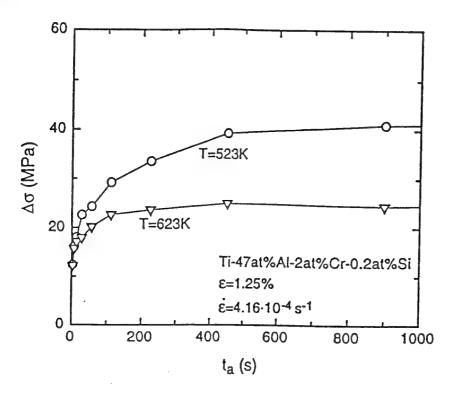


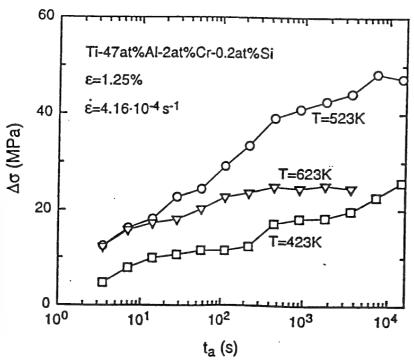
Ti-49 Al + 1200 wt. ppm C

comparison with Ti-47AI-2Cr-0.2Si

stress increments $\Delta \sigma$ due to strain ageing

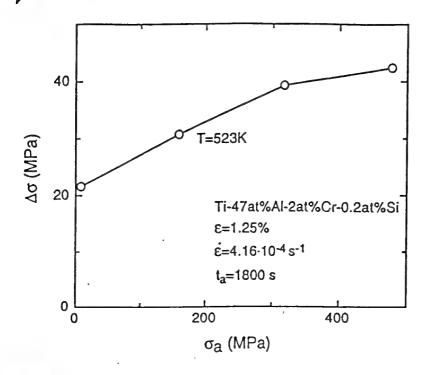
dependence on ageing time ta



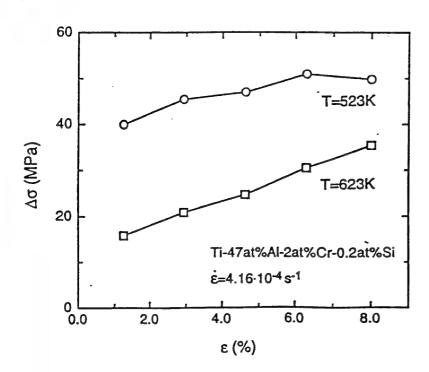


stress increments $\Delta \sigma$ due to strain ageing:

dependence on ageing stress σ_a

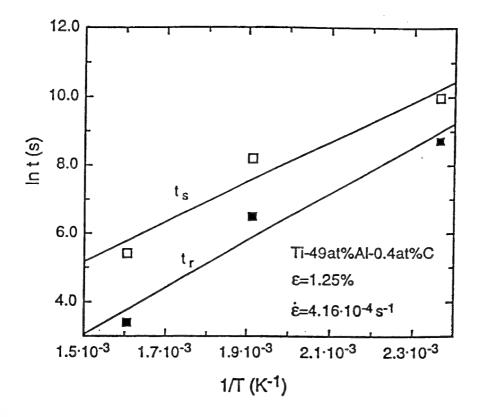


dependence on strain ε



evaluation of the kinetics $\Delta\sigma$ (ta):

saturation values
$$\Delta \sigma_s = f(T)$$

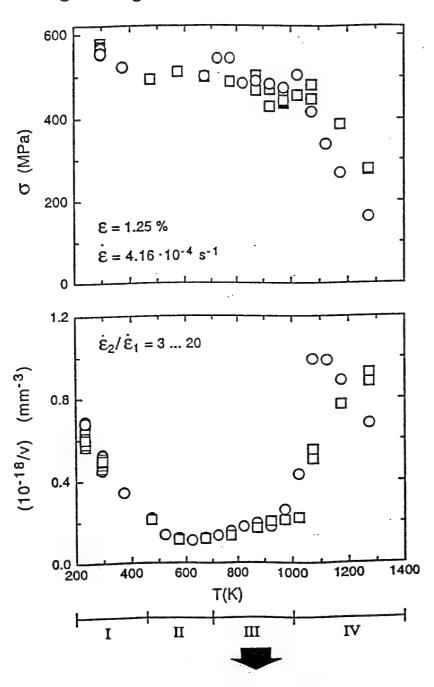


alloy -	ΔG (eV).
Ti-47Al-2Cr-0.2Si	0.47
Ti-49Al-0.4C	0.55

Flow stresses and activation volumes

$$\tau^* = (1/V) (\Delta F^* + kT \ln a/a_0)$$

Ti-47 at.% Al-2 at.% Cr-0.2 at.% Si O near gamma, □ nearly-lamellar



activation parameters

Activation parameters

Region III: 700...1000 K

strong increase of 1/V with T

$$\tau^* = (1/V) (\Delta F^* + kT \ln \dot{a}/\dot{a}_0)$$

nearly lamellar microstructure:

$$T = 900 K$$

$$\sigma = 480 \text{ MPa}$$

$$V = 200 b^3$$

$$\Delta G = 3.2 \text{ eV}$$

Comparison: self-diffusion energy

$$Q_{SD} = 3,01$$
 eV (Kroll et al., Brossmann et al.)

diffusion controlled mechanisms at the transition from brittle to ductile material behaviour?



implications on high-temperature strength

Activation parameters

Region III: 700...1000 K

strong increase of 1/V with T

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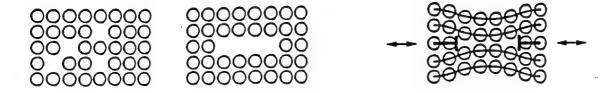


implications on high-temperature strength

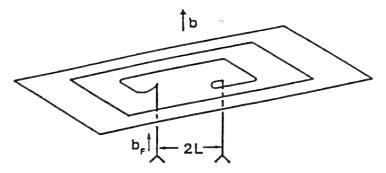
Implications on high-temperature strength

operation of Bardeen-Herring type dislocation climb sources

nucleation and growth of prismatic loops:



regenerative climb sources (source attached to dislocations having screw components):

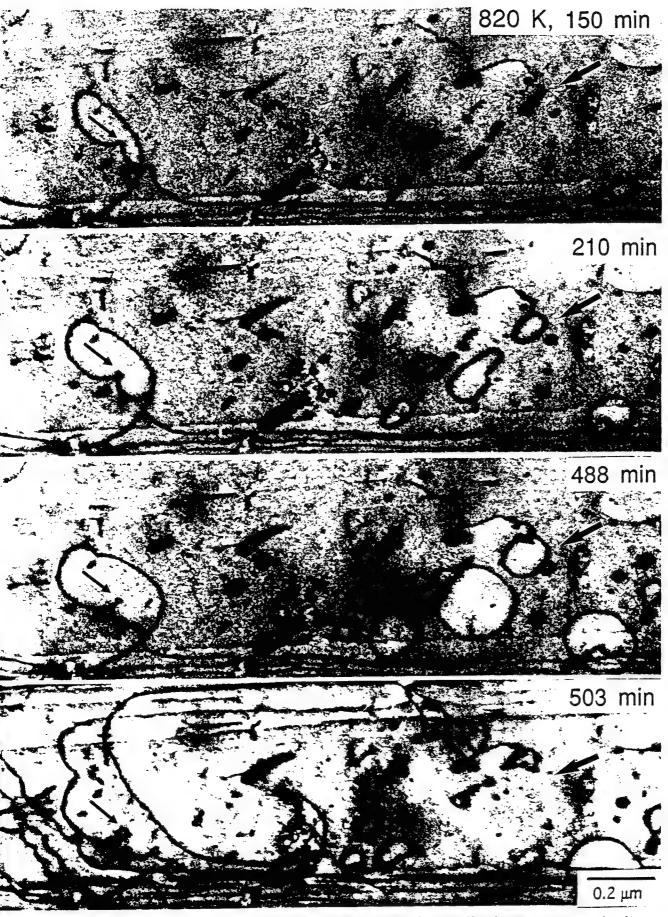


formation of helical dislocations





TEM in situ observations



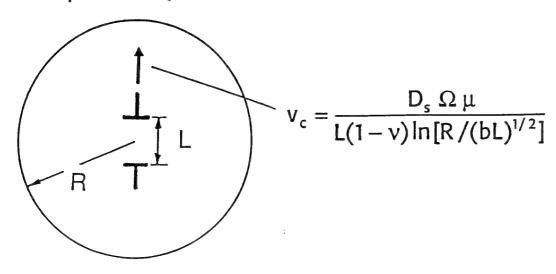
Operation of Barden-Herring type dislocation climb sources during in situ heating inside the TEM.

Ti-48Al-2Cr; acceleration voltage 120 kV, (400 T: 1937, 39, 47, 48)

Evaluation

vacancy source - and sink interaction (Hirth/Lothe 1992)

creep velocity of either dislocation



present situation: $R = 10^4b$, $L = 10^2 - 10^3b$

T (K)	v (mm/s)	D_s (m ² /s)
820	2.4 x 10-9	5 x 10-21
900	2 x 10-7	2 x 10-19

comparison: T = 1173 K

 $D_s = 10^{-17} - 10^{-15} \text{ m}^2/\text{s}$ (Ouchi et al., Kroll et al.)

Evaluation

vacancies supersaturation required to operate a Bardeen-Herring source of length L (Hirth, Lothe 1992)

$$\ln (c/c_o) = \frac{\mu b \Omega}{L 2\pi (1-\nu) kT} \ln (L\alpha/1.8 b)$$

present situation: $\alpha = 4$

$$\Omega$$
 = b^3 , μb^3 = 9.5 eV, T = 820 K, L = 150 - 350b

$$c/c_0 = 3 - 1.7$$

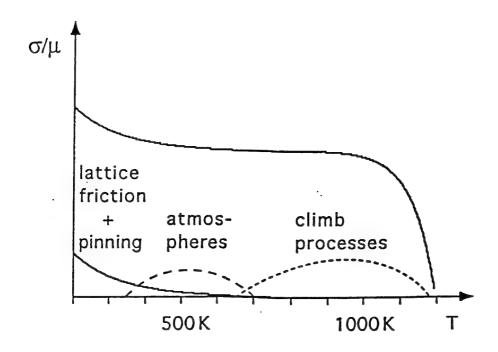
- small supersaturation in comparison with those met in rapid quenches (c/c₀ ~10⁴)
- Bardeen-Herring sources can probably operate throughout the period of fast cooling

Conclusions

Two-phase titanium aluminide alloys of technical significance contain a relatively high level of impurities, such as O, N and C, which impede dislocations due to solution and precipitation hardening.

At temperatures around 500 K dislocation locking occurs due to atmospheres of yet unknown defects.

Among different alloys the effects of these mechanisms are distinguished only quantitatively.



Interface - related deformation phenomena

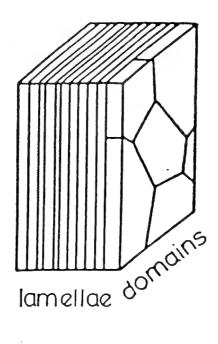
- structure and stress state of lamellar interfaces
- translation of shear deformation across interfacial boundaries
- crack propagation



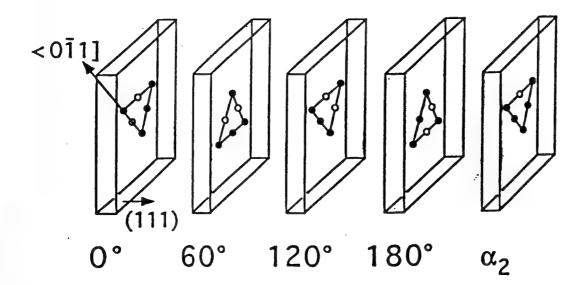
Related problems:

- poor ductility at ambient temperatures
- insufficient resistance against creep and recrystallization at high temperatures

Structural features of lamellar interfaces



- γ phase: domain structure of six ordered variants
- tetragonality of the γ phase c/a = 1.02



HREM Observation of lamellar interfaces

Interfaces types:

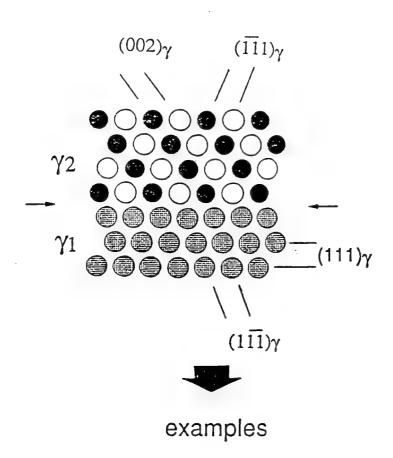
 α_2/γ

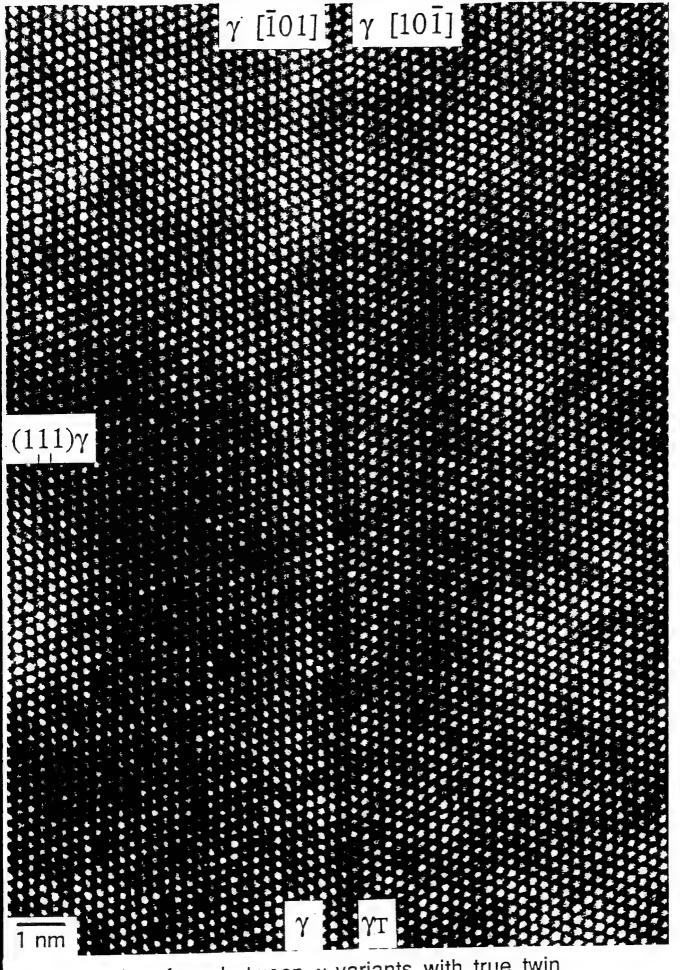
 γ/γ_T true twin

 γ_1/γ_2 matrix/matrix

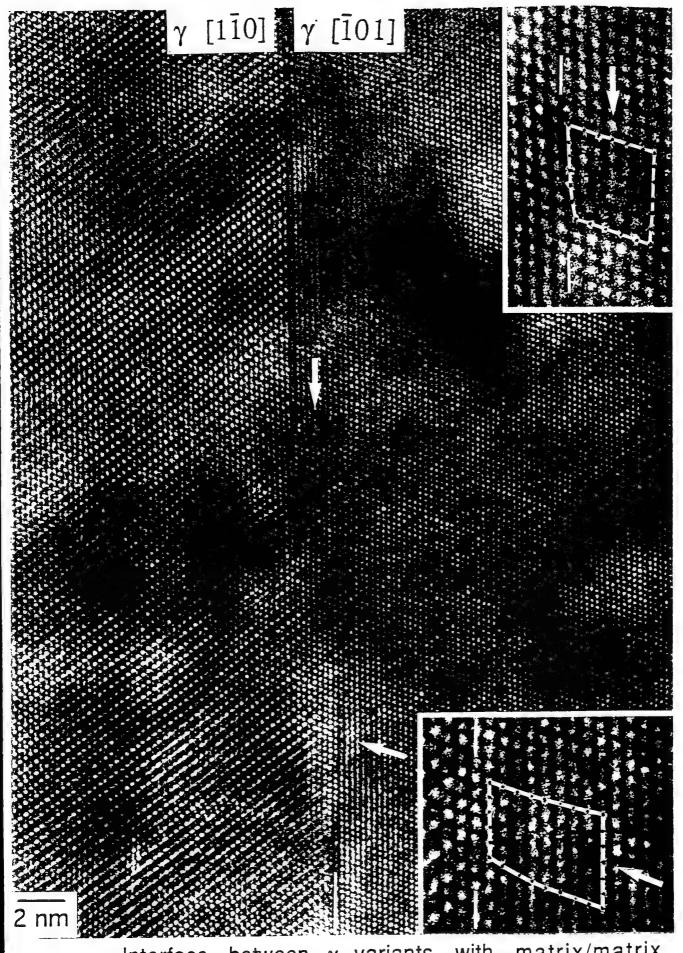
 γ_1/γ_2 pseudo-twin

<101> projection of the pseudo-twin:

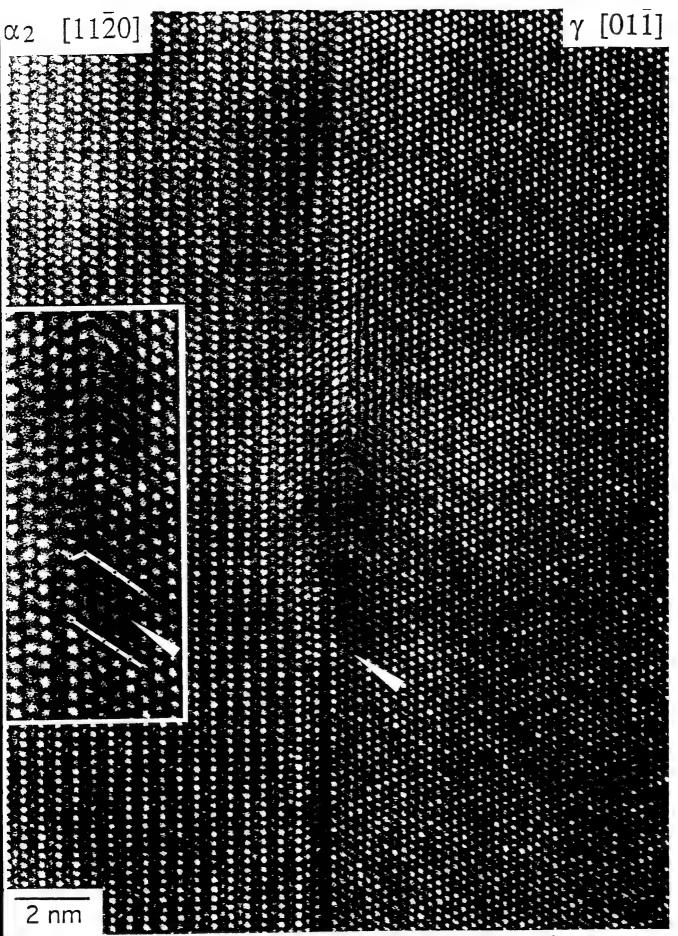




Interface between γ variants with true twin orientation; Ti-48at.%Al-2at.%Cr. (CM 4204)



Interface between γ variants with matrix/matrix orientation; Ti48-at.%Al-2at./%Cr. (CM 4232)



 α_2/γ interface in a Ti-48at.%Al-2at.%Cr alloy. Creep deformation: σ = 140 MPa, T = 700 °C, t = 6000 h, ϵ = 0.69%. (CM 4278)

Stress state of lamellar interfaces

- lattice mismatch largely accommodated by misfit dislocations
- residual homogeneous straining of adjacent lamellae



long-range internal stresses τ at the interfaces

Origin of the residual stresses

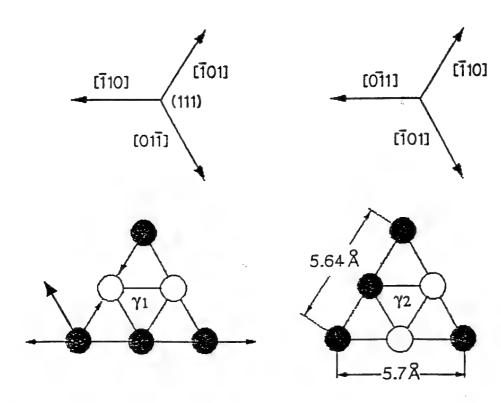
- lattice mismatch at semicoherent interfaces $\Delta \varepsilon = 1 ... 2 \%$
- largely accommodated by misfit dislocations
- residual homogeneous straining Δε, of adjacent lamellae
- high elastic stiffness of γ -TiAl, μ = 4.3 · 104 MPa



long-range residual stresses at the interfaces: $\tau = \Delta \epsilon_r \cdot \mu$

Origin of the residual stresses

Atomic arrangement of the $(111)\gamma$ planes at an interfaces between γ lamellae with pseudo-twin relation



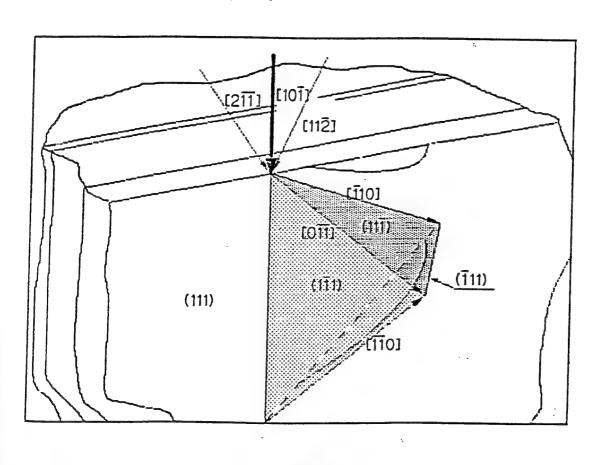
- pure shear deformation along [011],
- resolved into shear stresses acting on <110> {111} slip systems of the adjacent lamellae



schematic drawing and example

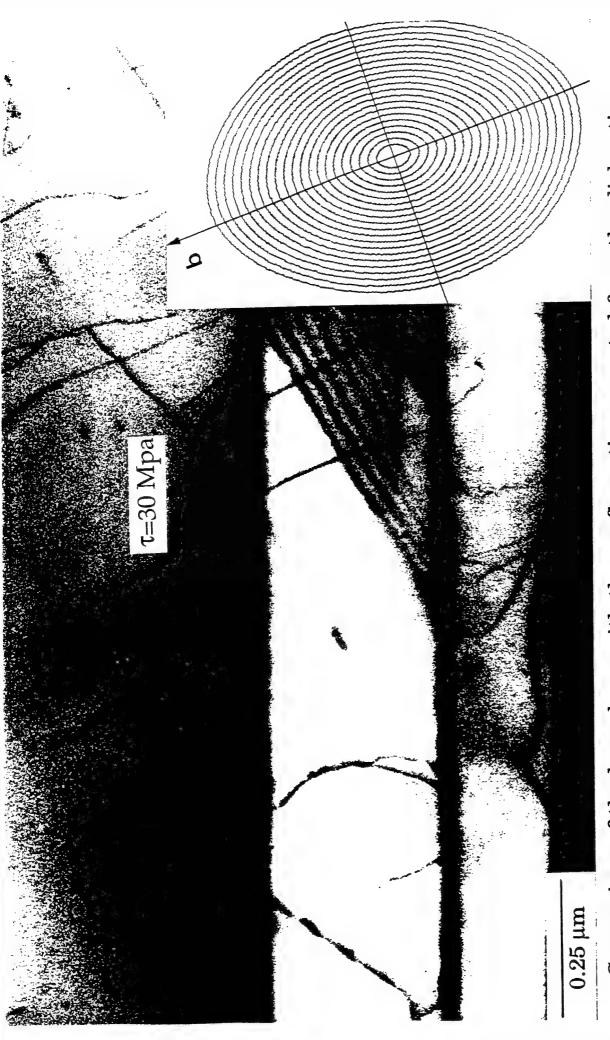
Stress state of lamellar interfaces

Coherency stresses at semicoherent (111) γ interfaces, resolved into shear stresses τ acting on <110>{111} slip systems





experimental observation, comparison with line tension configurations



Comparison of the loop shape with the configuration expected from the dislocation line tension model (CM 1472)

The dislocation line tension model

DE Witt and Koehler

$$T = [\mu b^2/4\pi(1-v)][\ln(R/r_0) + C(\Theta)]$$

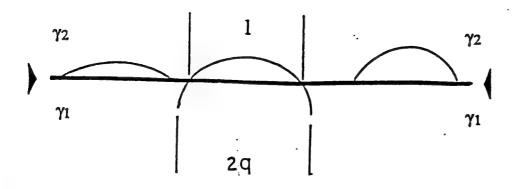
$$R = 1/5$$
, $r_o = b/8$ (Hirth, Lothe)

$$q = [\mu b/4\pi(1-v) \tau][\ln 1 + \ln (8/5b)]$$

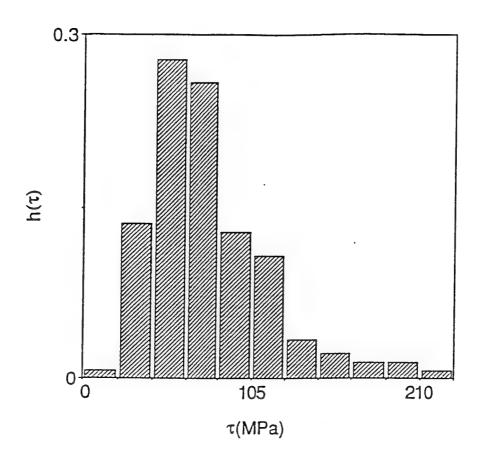
 $\tau = const.$

$$q = E' \ln 1 + D$$

Evaluation:



Stress state of lamellar interfaces



Distribution of the internal stresses τ acting on dislocation loops emitted from interfacial boundaries.

Comparison with deformation experiments:

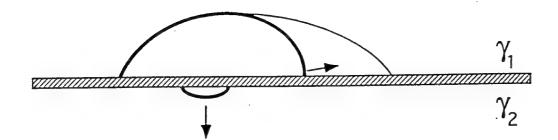
$$\sigma_a$$
 = 430 MPa \rightarrow τ_a = $\sigma_a/3$ = 140 MPa τ = 20 ... 220 MPa

Consequences:

- high density of dislocation sources
- relaxation of local stress concentrations
- contribution to glide and climbing processes

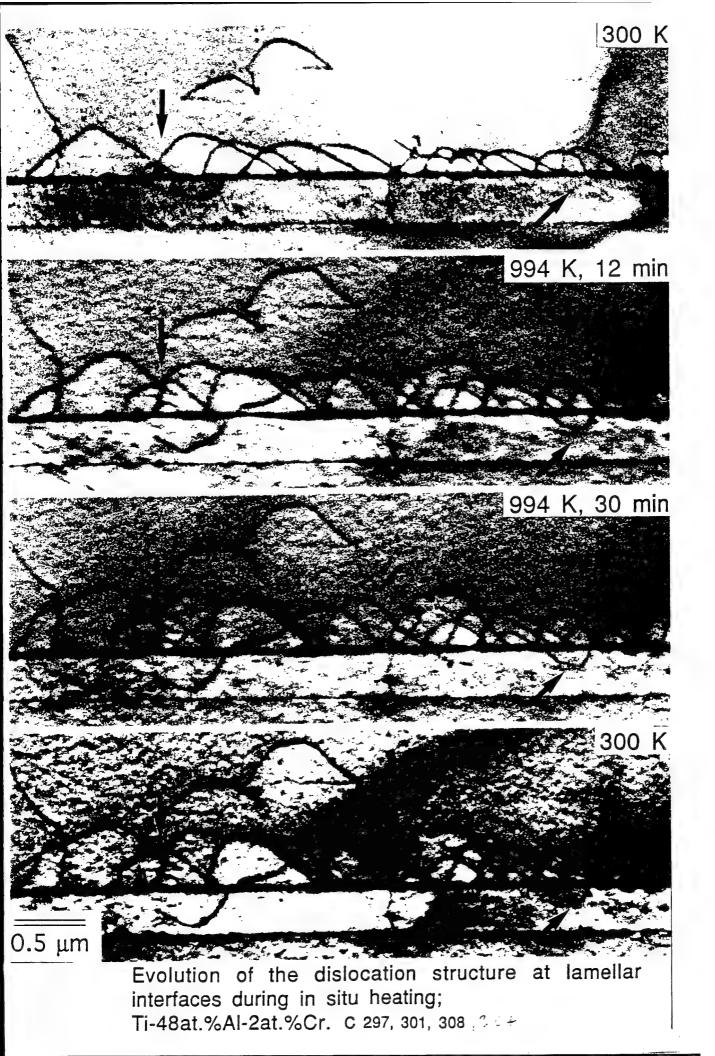
Interfaces as dislocation sources

- Dislocation segments strongly bowed out due to coherency stresses and thermal stresses
- friction forces impede propagation
 - unzipping and generation of new loops at elevated temperatures



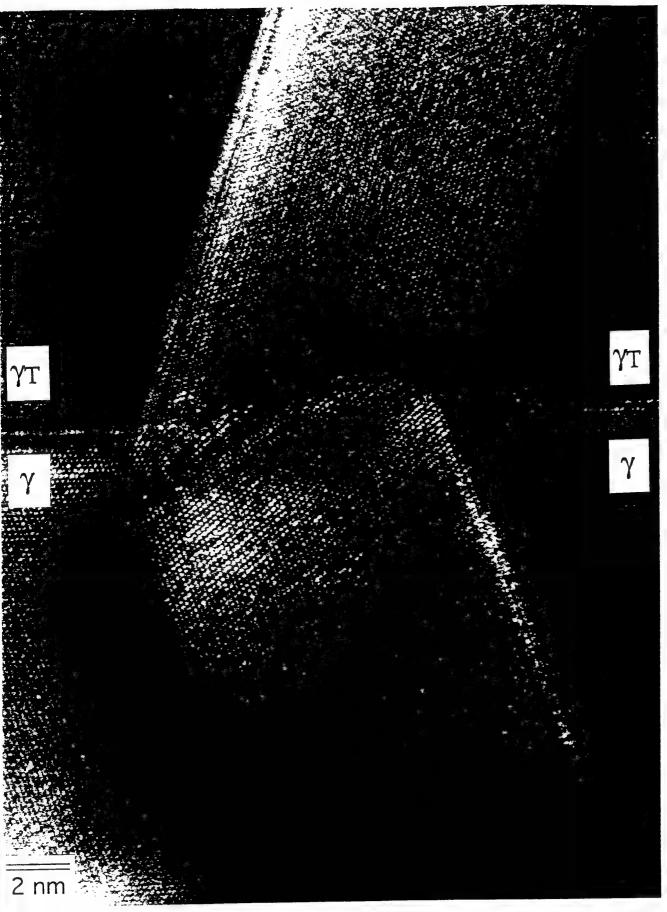


TEM in situ heating study



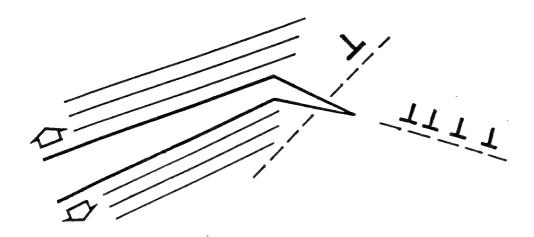


Dislocation glide processes initiated at semicoherent interfaces in a two-phase $(\alpha_2+\gamma)$ TiAl alloy. Deformation at room temperature (CM3569).



Translation of twinning deformation through an interfacial boundary γ/γ_T between lamellae with true twin relation. T = 300 K, ϵ_f = 0.2% (3A5743)

Crack Propagation



Possible Processes:

- lattice decohesion
- crack deflection
- crack tip blunting
- crack tip shielding
- formation of a plastic zone



TEM: Interaction of cracks with lamellar interfaces

Crack propagation

Inverse correlation between ductility and fracture toughness in $(\alpha_2 + \gamma)$ titanium aluminide alloys

Kim and Dimiduk 1991, Chan and Kim 1992

Fully-lamellar microstructures: Low ductility/high toughness

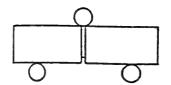
Duplex microstructures: High ductility/low toughness



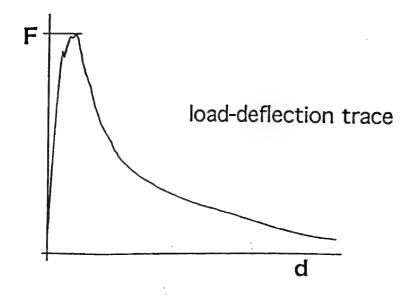
Fracture toughness of lamellar $(\alpha_2 + \gamma)$ TiAl

Fracture toughness of $(\alpha_2 + \gamma)$ TiAl

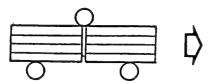








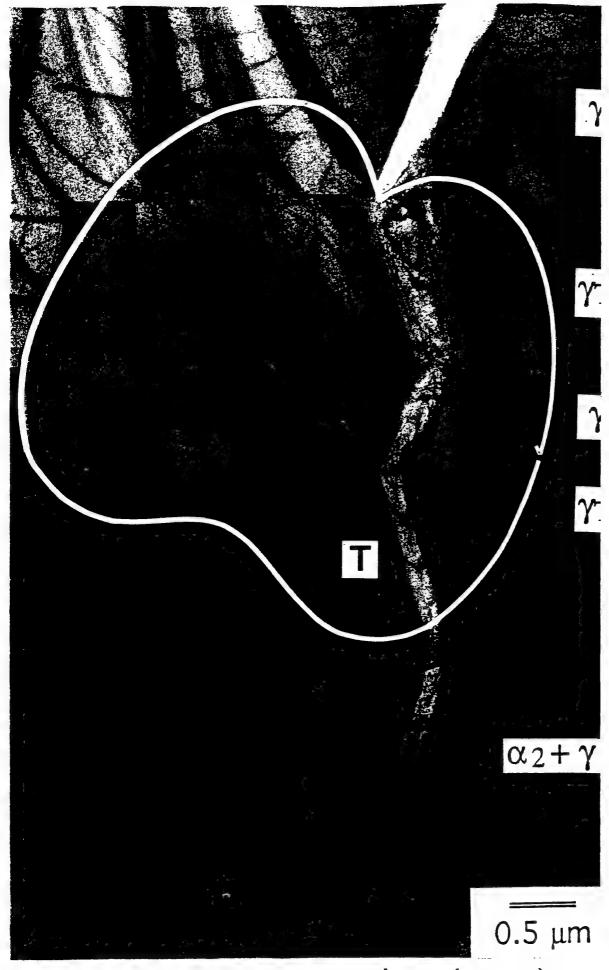
$$K_{Ic} = 15.2 \pm 2.3 \text{ MPa m}^{1/2}$$



$$K_{lc} = 22.1 \pm 1.9 \text{ MPa m}^{1/2}$$

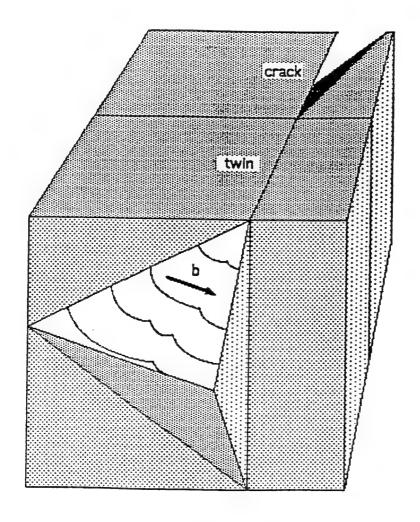


TEM: interactions of crack tips with lamellar interfaces

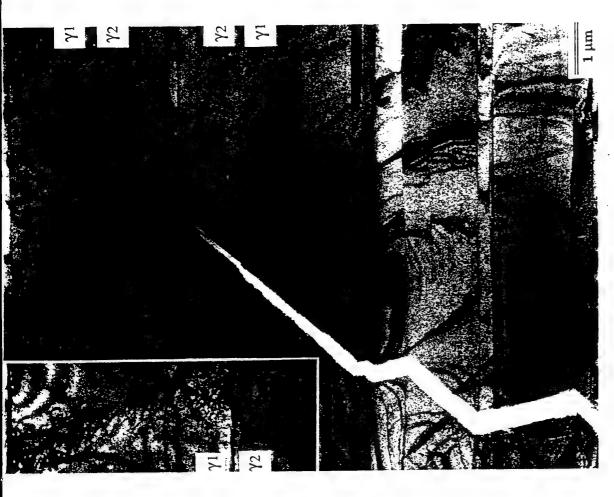


Crack propagation in a two-phase ($\alpha_2 + \gamma$) TiAl alloy with a duplex microstructure

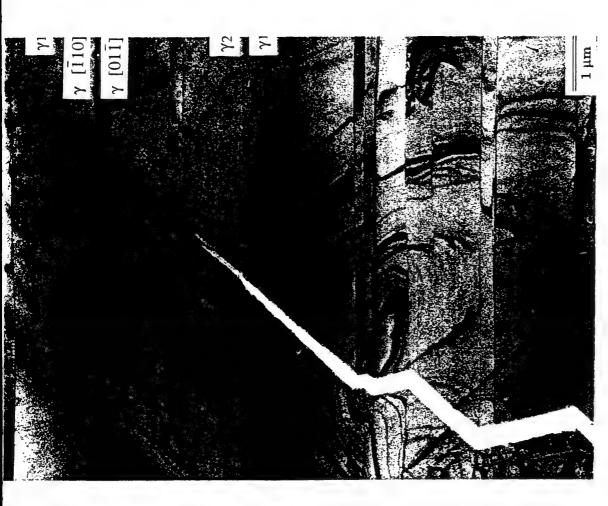
Crack Propagation



- {111} cleavage planes
- twinning precedes crack propagation
- immobilisation at semicoherent interfaces
- shielding of the crack tip, τ = 70 ... 290 MPa



Crack propagation in a two-phase $(\alpha_2+\gamma)$ titanium aluminide alloy (CM 3293, CM 3334).



Crack propagation in a two-phase $(\alpha_2 + \gamma)$ titanium aluminide alloy (CM 3293).



Shielding of a crack tip in a two-phase $(\alpha_2+\gamma)$ titanium aluminide alloy by deformation twins and (1/2) <110] dislocations (CM 3334).

Conclusions

The deformation behaviour of $(\alpha_2+\gamma)$ titanium aluminides is closely related to lamellar interfaces.

Semicoherent α_2/γ and γ/γ interfaces are characterized by a high density of misfit dislocations and residual coherency stresses.

These structural features support the generation of glissile dislocations and of a fine dispersion of deformation twins.

The generation mechanisms of dislocations and twins are involved in the translation of shear deformation across lamellar boundaries and contribute to stabilize crack propagation.

The low ductility of the material seems therefore not to result from a lack dislocations but from their insufficient mobility.

Implications on creep resistance

design requirements regarding long term creep resistance:

T= 700 °C, σ = 150 MPa, t = 10.000 h \rightarrow ϵ ≤ 1%, nominal creep rate $\dot{\epsilon}$ ≤ 10-10s-1 not yet fulfilled

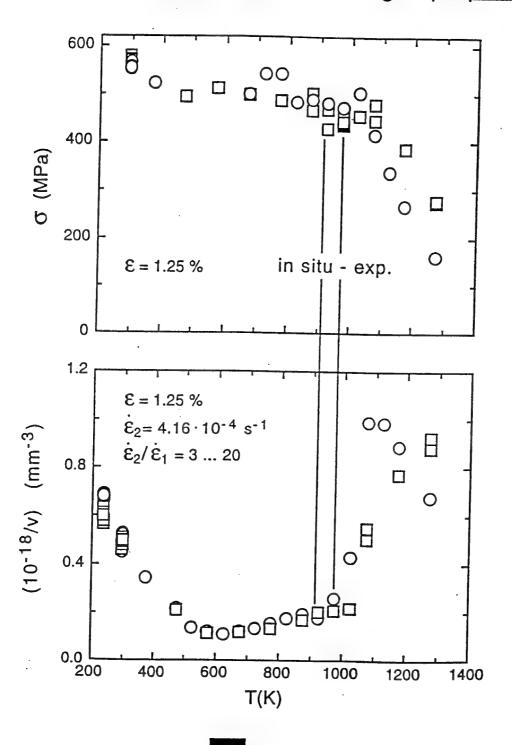
- problem: fast primary creep
- potential mechanisms: non-conservative dislocation processes, structural changes



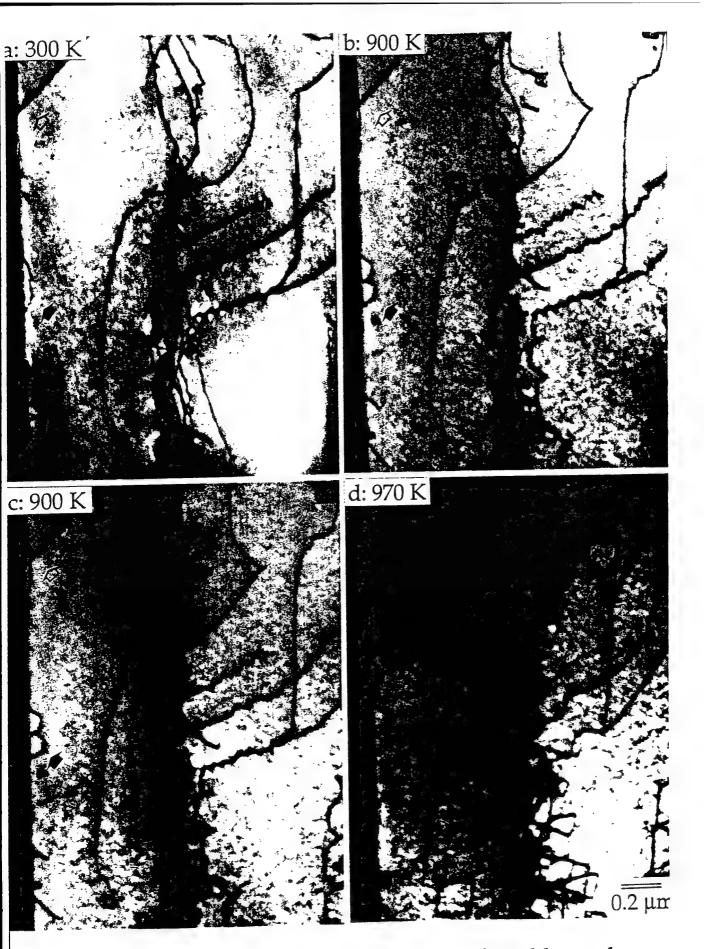
TEM-observations on lamellar Ti-48 at.% Al-2 at.% Cr

- in situ heating studies
- defect structure of samples crept at T= 700 °C, σ = 150 MPa for 6000 h to ϵ = 0.69% nominal creep rate $\dot{\epsilon}$ = 3 x 10-10s-1

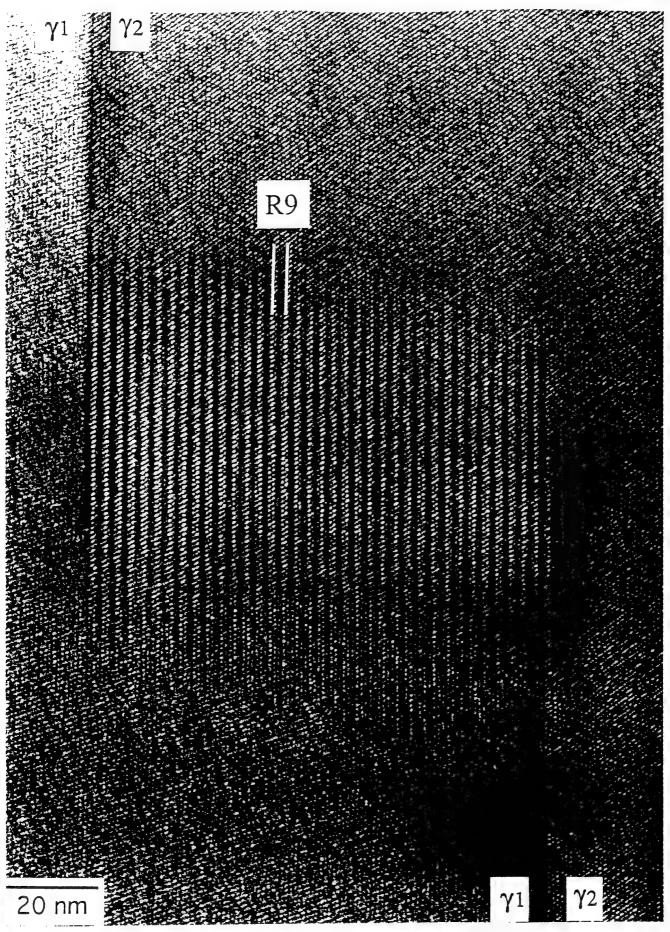
In situ heating experimentrelationship to strength properties



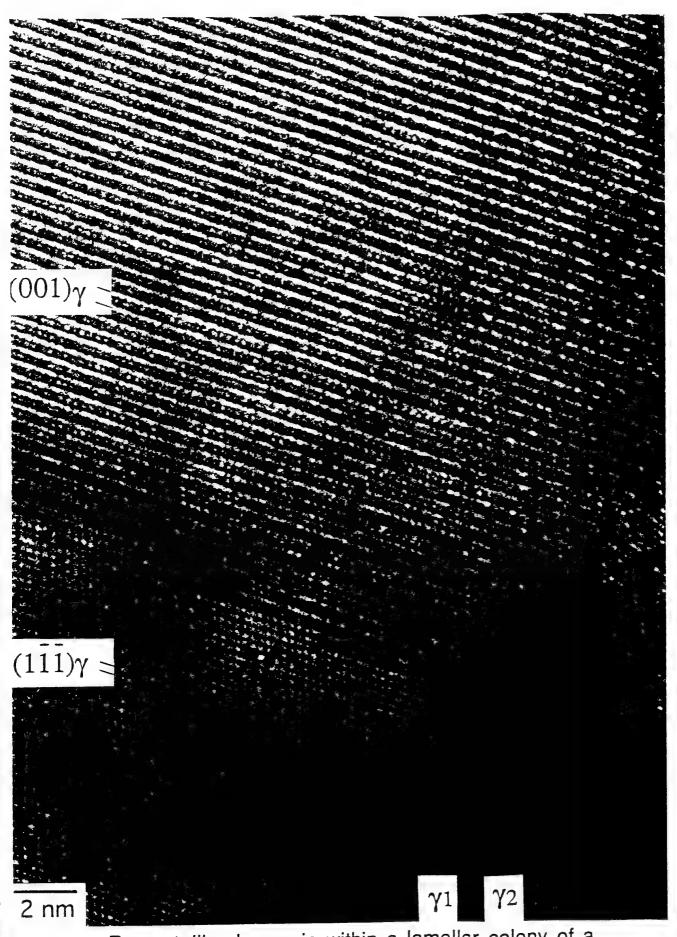
in situ study, T = 900 - 970 K



Dislocation loops emitted from an interfacial boundary during in situ heating inside the electron microscope (400 T 691, 694, 695, 698)



Formation of the R9 structure at a ledge in a semicoherent interface of a Ti-48at.%AI-2at.%Cr alloy. Creep deformation: σ = 140 MPa, T = 700 °C, t = 6000 h. ϵ = 0.69%. (CM 4178)



Recrystallized γ grain within a lamellar colony of a Ti-48at.%Al-2at.%Cr alloy. Creep deformation: σ = 140 MPa, T = 700 °C, t = 6000 h, ϵ = 0.69%. (CM 4214)



Recrystallized γ grain within a lamellar colony of a Ti-48at.%Al-2at.%Cr alloy. Creep deformation: σ = 140 MPa, T = 700 °C, t = 6000 h, ϵ = 0.69%. (CM 4216)

How to improve high-temperature strength?

many metallurgical factors have to be considered: grain size, alloying additions, phase distribution and stability etc.

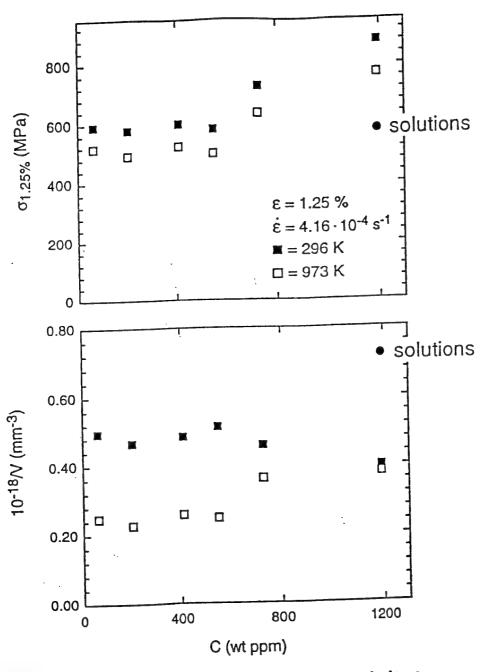
- regarding present observations:
- dislocation glide and climb should be impeded
- structural changes have to be prevented during service
- potential mechanisms: dislocation locking due to solutions, precipitates, ageing



flow stresses and activation volumes of Ti-49 at.% Al + (60 - 1200) wt.ppm C, thermal treatments for solution and precipitation of C and N

Precipitation hardening in γ(TiAl) containing carbon and nitrogen

Ti-49 at.% Al + (60 - 1200 wt.ppm C



 hardening due to large precipitates, athermal contribution to flow stress



Deformation structure of a Ti-49 at.% Al-0.4 at.% C alloy. Compression at 300 K to strain $\epsilon=3$ %. (CM 5858)



Interactions of deformation twins with Ti₃AIC precipitates. Ti-49 at.% Al-0.4 at.% C. Deformation at 300 K to $\epsilon=3$ %. (CM 5845)

Interactions of deformation twins with Ti₃AIC precipitates. Ti-49 at.% Al-0.4 at.% C. Deformation at 300 K to $\epsilon=3$ %. (CM 5807)

Conclusions

degradation of strength properties of twophase titanium aluminides at elevated temperatures due to

- non-conservative dislocation mechanisms
- · dislocation multiplication by climb sources
- significant changes of the microstructure, particularly during long-term creep loading

potential mechanism to improve high-temperature strength: hardening due to Ti₃AlC precipitates

problems:

- thermal stability of precipitates during service
- balanced properties of low-temperature ductility and high temperature strength

Design against fracture and fatigue in TiAl-based aluminides

Paul Bowen Professor of Mechanical Metallurgy

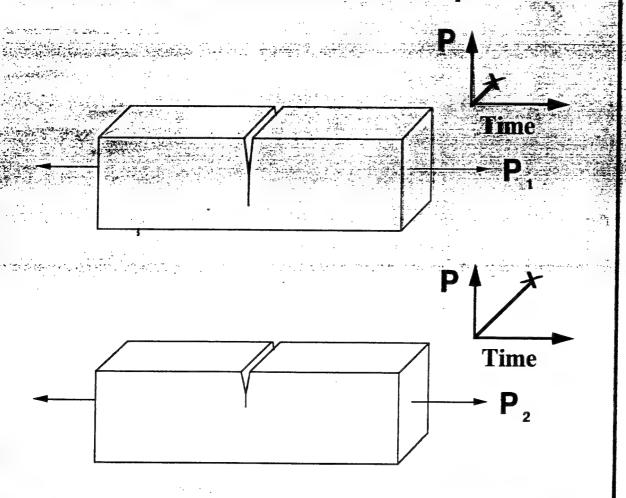
School of Metallurgy and Materials/IRC The University of Birmingham

Issues

- 1. Lower bound fracture toughness values in fullylamellar microstructures
- 2. Crack growth resistance curves and the use of defect tolerance design
- 3. Total life: traditional concepts of S-N curves
- 4. Problems:
- i) sampling volume
- ii) stress concentrations
- 5. Microstructural features:
 - i) lamellar plate thickness
 - ii) lamellar colony size

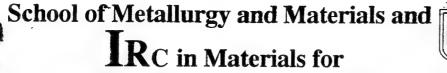
Design against failure

Accept materials contain sharp defects



At failure P₁ < P₂ (easy to understand)

But ask how much can $P_2 > P_1$ and still be safe?



UNIVERSITY COLLEGE High Performance Applications



Simple Analysis (Fracture Mechanics)

$$\mathbf{K} = \sigma \left(\pi \, \mathbf{a}\right)^{1/2}$$

Material Failure Limit

Stress

Applied Defect size, life defined by raie of growth

Engineering:

predict value of K for range of

crack sizes, shapes and stress

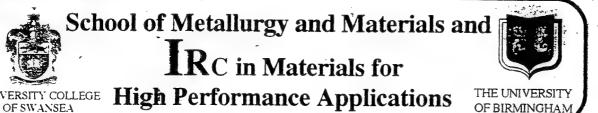
fields

Metallurgy/Materials Science : control K failure

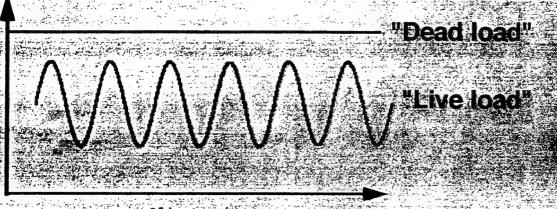
(Understand microstructural size scale)

Failure: Brittle

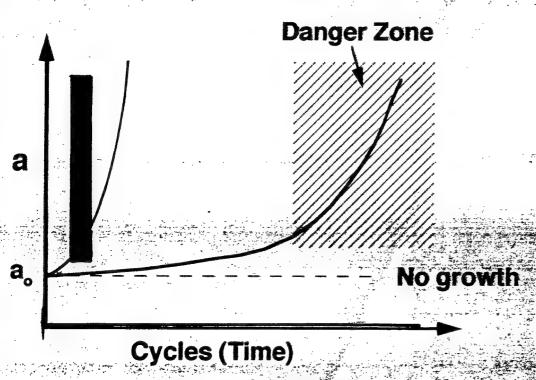
Ductile



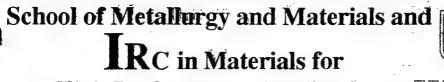




time ► Failure only under live load



a_o = initial defect population



HINC in Materials for High Performance Applications



Simple Crack Growth Laws:

 $da/_{dN} = A \Delta K^{m}$

Rate of crack growth

Driving force

A, m are material's "constants"

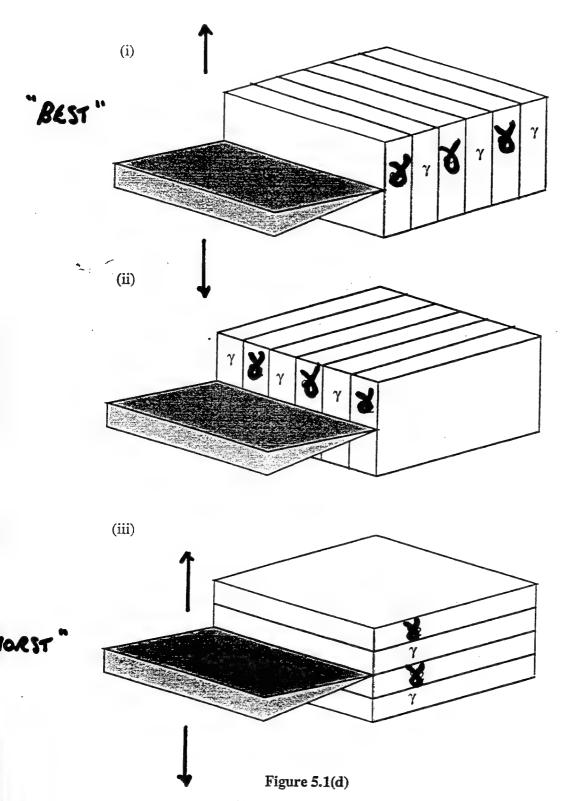
Conventional materials m = 2 - 4

Intermetallics, ceramics m upto 50



School of Metallurgy and Materials and **IR**C in Materials for VERSITY COLLEGE High Performance Applications





Orientation relationship between the crack and the lamellar microstructure.

(i) Crack arrester orientation, (ii) Crack divider orientation and (iii) crack delamination orientation.

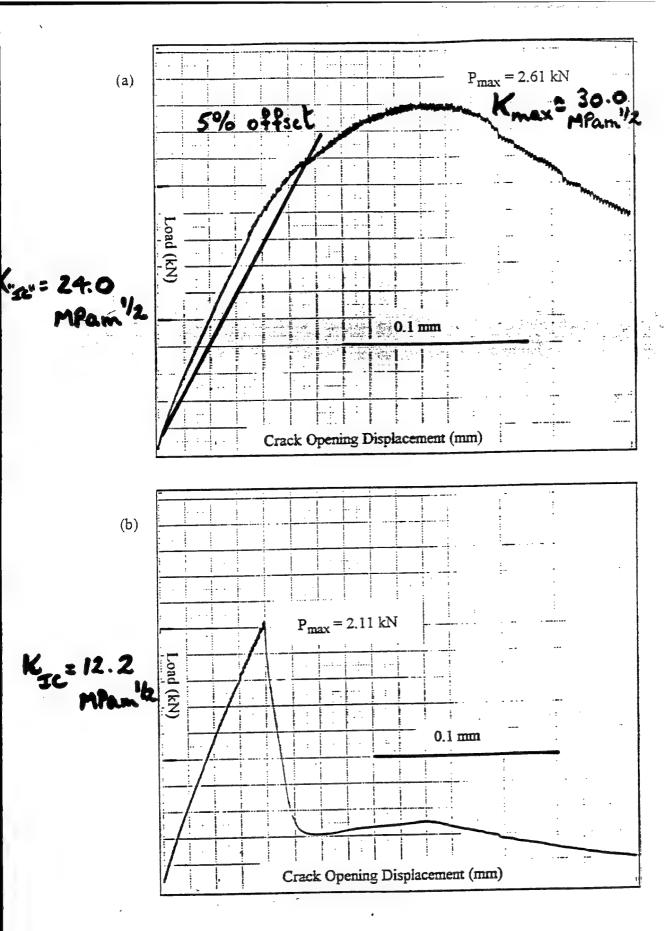
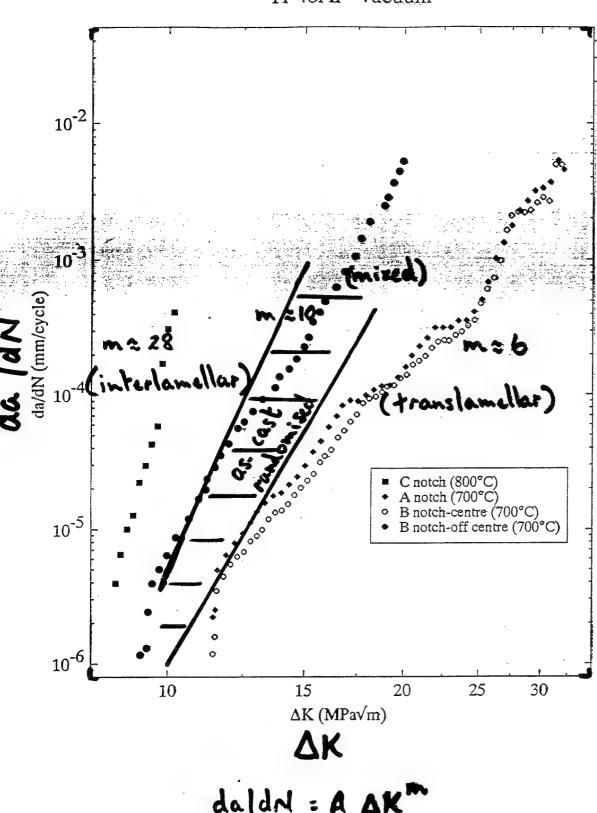


Figure 6.6

Clip gauge opening displacement versus load traces for fracture toughness tests performed in air at ambient temperature.

(a) translamellar failure and (b) interlamellar decohesion.

Ti-48Al - vacuum



daldn = A DK

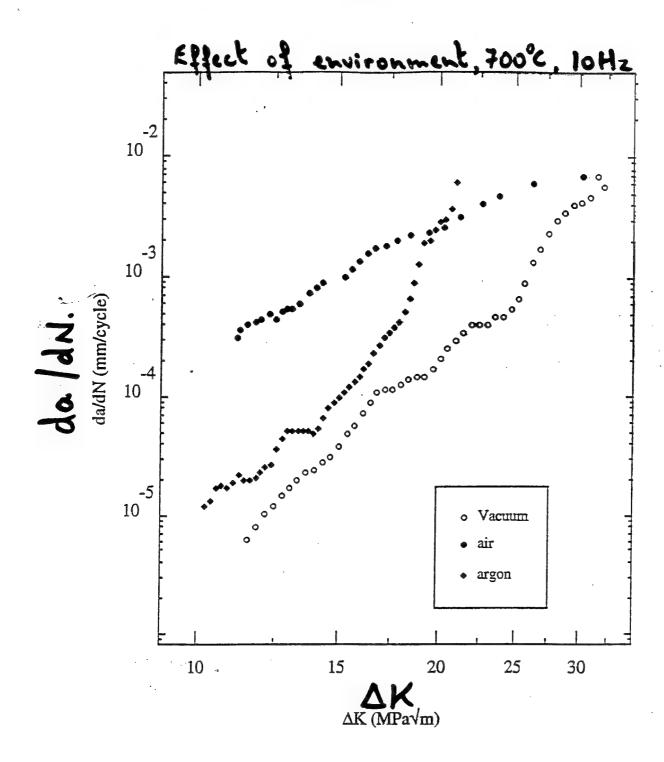
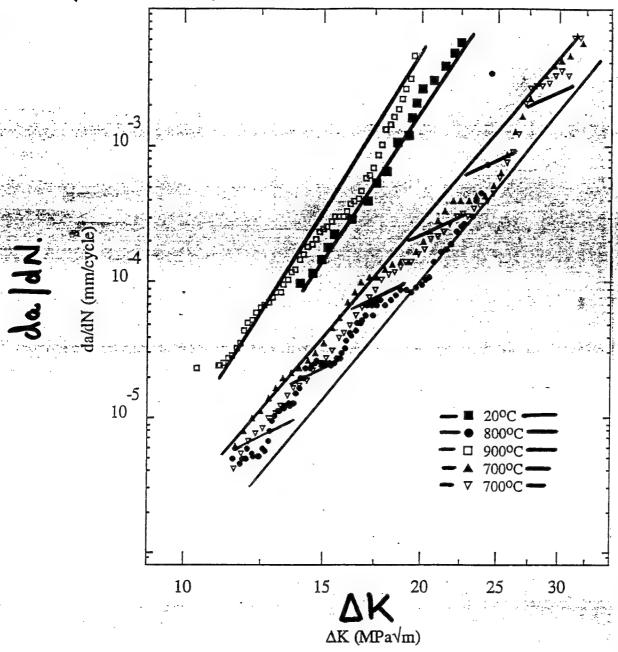


Figure 6.8

Fatigue crack growth resistance curves - da/dN versus ΔK for 'as cast' Ti-48Al tested at a temperature of 700°C as a function of environment.

FULLY TRANS LAMELLAR FAILURE

fects of test temperature (in vacuum).



(* indicates transverse testpiece with type (ii) notch)

Figure 6.9

Fatigue crack growth resistance curves - da/dN versus ΔK for 'as cast' Ti-48Al tested in vacuum at temperatures of 700,800 and 900°C.

(Unusual trend compared with conventional alloys).

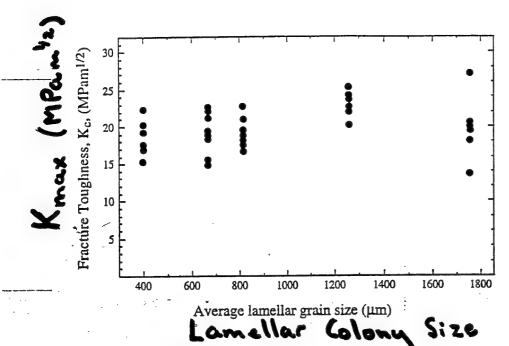


Figure 10. Variation of K_C values with colony size (fully lamellar microstructure-randomised colonies).

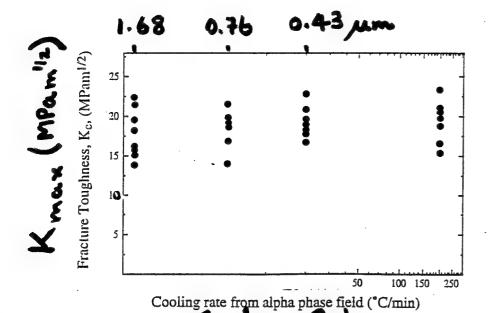


Figure 11. Variation of K_C values with plate thickness (fully lamellar microstructure-randomised colonies), see text.

ffects of lamellar colony size and lamellar plate thickness.

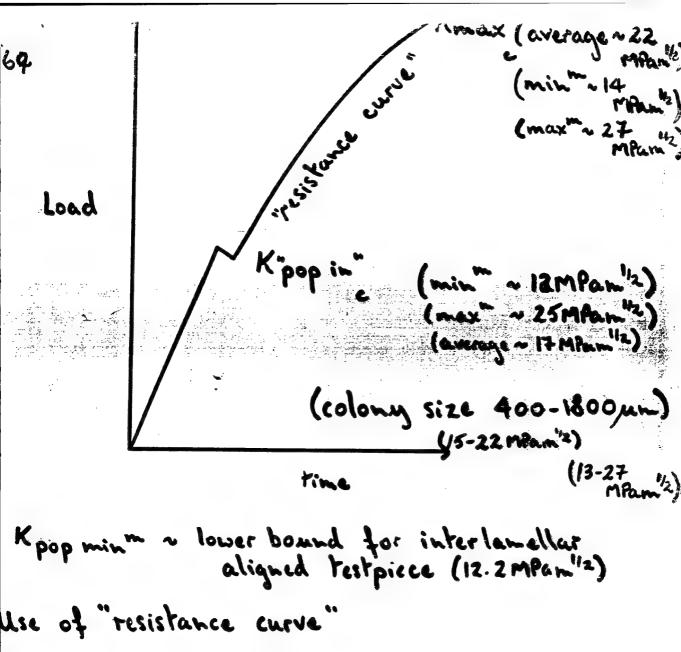
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Engineering sense

Use Kpop values even in "ductile" systems.

Need to ensure that microcracks do not join up

Need to utilise fatigue crack growth to

Jenerate resistance curve.

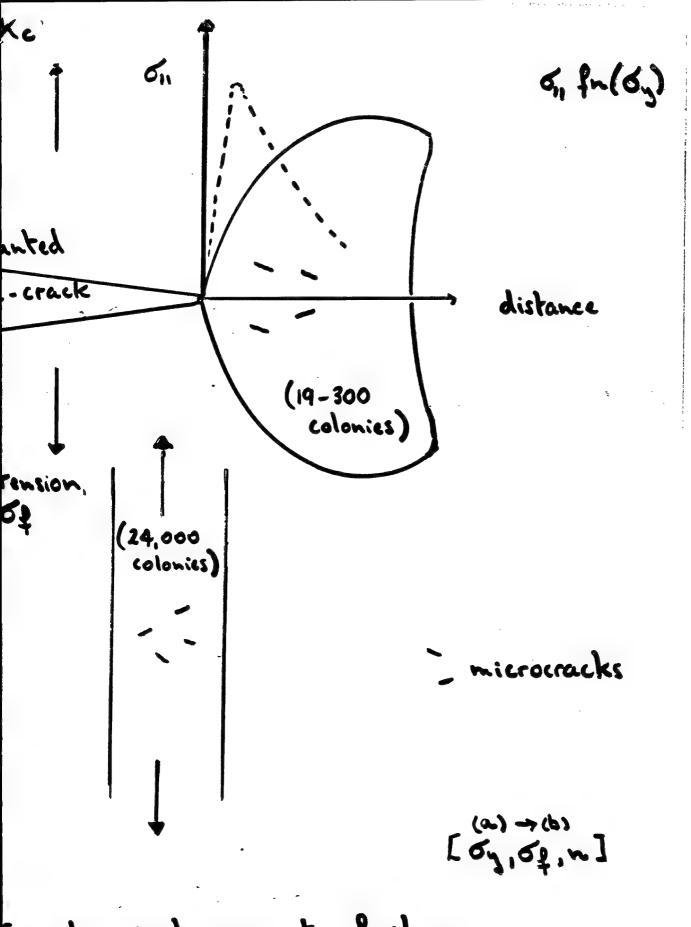
or above system variation in Kmax and Kpop is afrene for engineering alloy ? (weibull modulus ~ 7.8).

Process zone sampling	effects at	failure
Stresses > Of (tension)	over volume ellar colony ~ 40	sampled).
Fracture toughness test	No of "grains"	
34	V	1250-300
Kc = 25 MPa - 42	300	1250 - 300
Tensile test	No. of "grains"	on (MPa)
0f~ 300MPa	24,000	300

IB.

For coarse "randomised" (400 jun +) fully wellar, % El to failure and lower bound a value, are both lower than values stainable from duplex microstructures.

reep resistance of fully-lamellar microstructures still vastly superior to duplex microstructures?



Consider just prior to failure.

18. Steep daldy curve (high"m") => must design on total life (s-y curves).

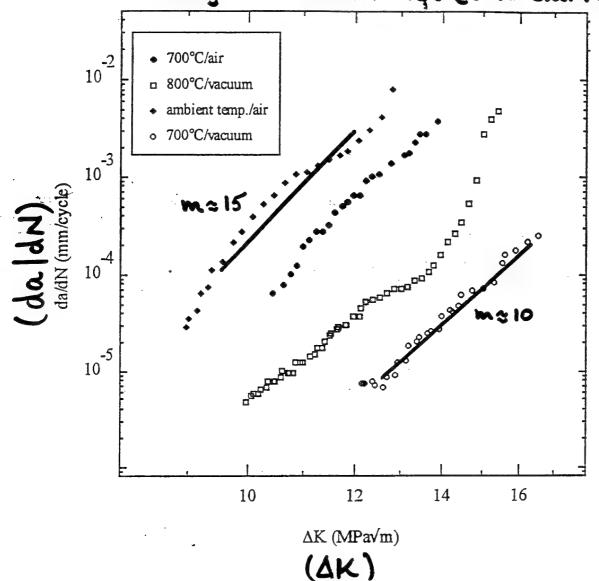
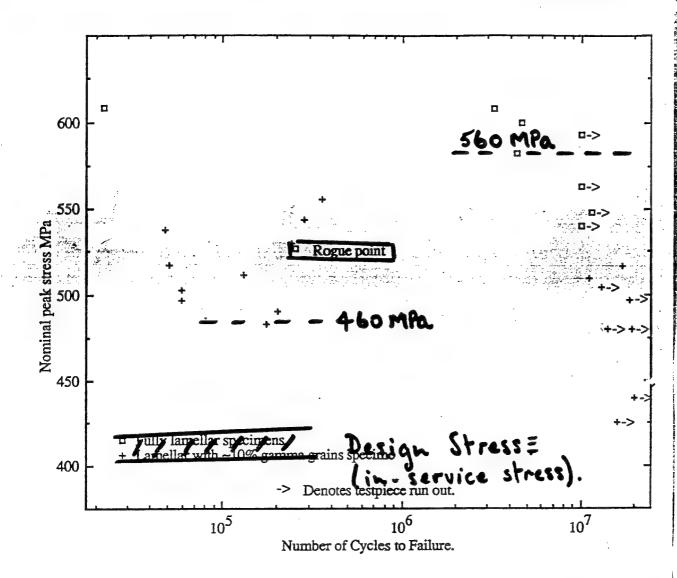


Figure 6.27

Fatigue crack growth curves da/dN versus ΔK for cast and HIPed XD rs gamma.

$$G_{0.2} = 340 \text{ MPa}$$
 (327-346 MPa)
 $G_F = 400 \text{ MPa}$ (383-415 MPa)
 $EP = 1\%$ (0.88-1.10%)
 $E = 160 \text{ GPa}$
 $K_c = 15-18 \text{ MPam}^{1/2}$

NB. Steep daldn v DK curves => flat 5-N curves.



S-N plots for ground and polished fully lamellar and near lamellar specimens.

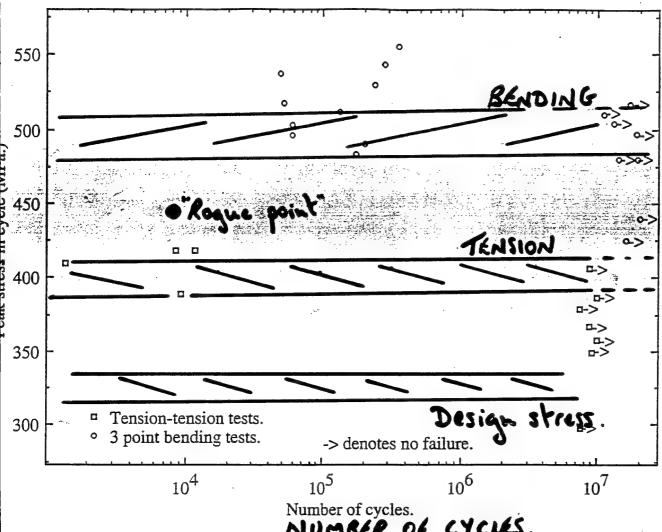
RUN OUT STRESS FOR FULLY LAMELLAR SPECIMENS = 560 MPa.

RUN OUT STRESS FOR LAMELLAR+10% GAMMA GRAINS = 460 MPa.

* care because of "roque point".

Steep daldN => flat s-N'curves"

Tension-Tension and 3 Point Bending

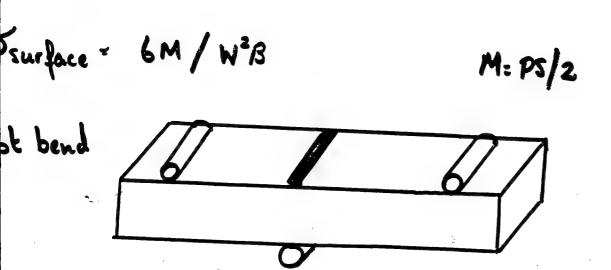


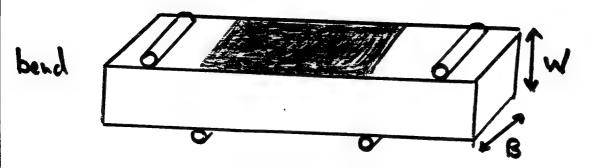
NUMBER OF CYCLES.

Run out stress for 3 point bending = 460 MPa.Run out stress for tension-tension = 380 MPa.(~0.95GP)

0.2% Proof Stress = 340MPa. Tensile Strength = 410MPa. (91)

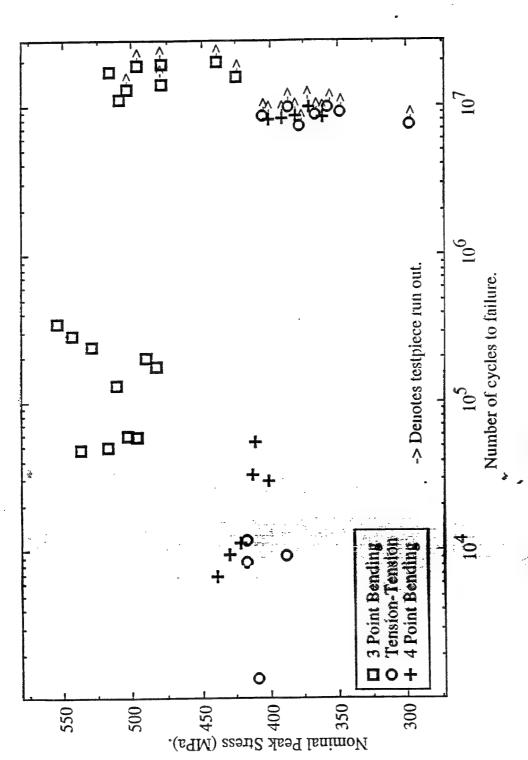
Surface area tension is x10 that in bending Yolume tension is x26 that in bending





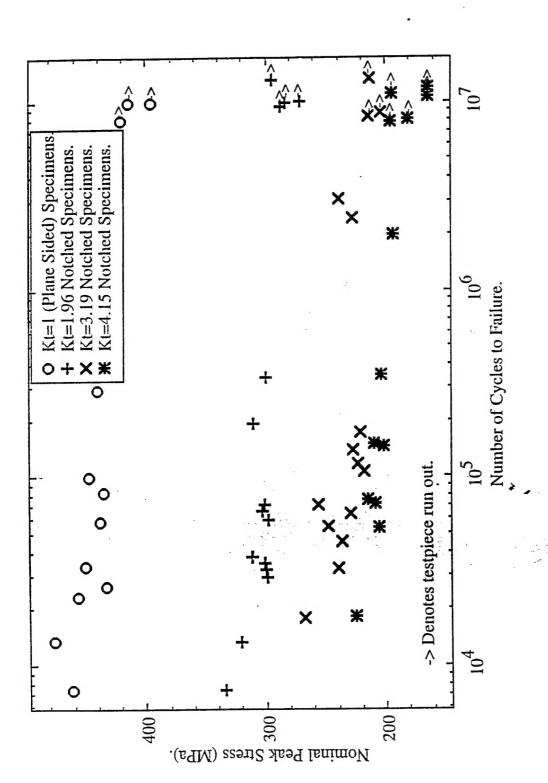
ension = MD × gauge length

Match for Ssurface > Orun-out in tension?



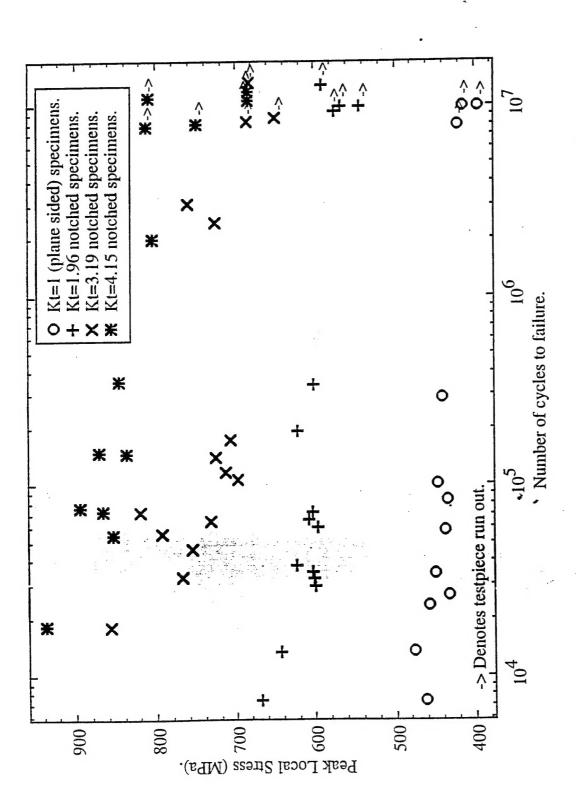
S-N plots of as-received ingot specimens tested in three and four point bending and tension-tension loading. Nominal peak stress vs. number of cycles to failure.

Figure 6.24



S-N plots of notched and plane-sided specimens machined with three passes of the EDM wire. Nominal peak stress vs. number of cycles to failure.

Figure 6.18



S-N plots of notched and plane sided specimen: machined with three passes of the EDM wire. Peak local stress vs. number of cycles to failure.

Figure 6.19

Conclusions

Strong microstructural effects on daldn's AK and Ke (brittle fracture).

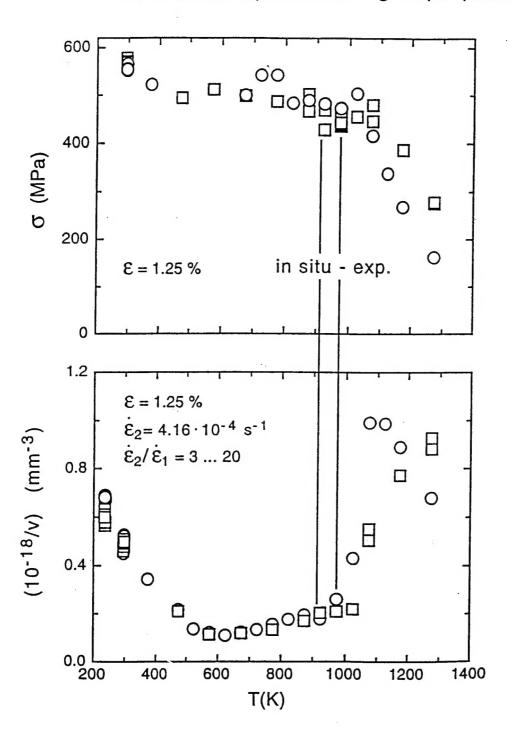
Fully lameller microstructures show promise. Care required because Ke and daldN vs &K can be highly anisotropic in as-cast microstructures.

Optimisation of fully lamellar, "fine" colony size required (randomised). Even then steep daldN vs DK, modest Kc (15MPam⁴²).

Use S-N approach but keep in-service stresses as low as possible (?notches).

Sampling arguments (stress and volume) need careful consideration.

In situ heating experimentrelationship to strength properties



in situ study, T = 900 - 970 K